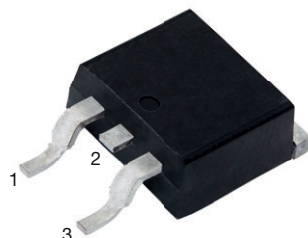
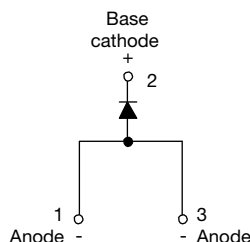


Surface Mount Fast Soft Recovery Rectifier Diode, 20 A


D²PAK (TO-263AB)


FEATURES

- Glass passivated pellet chip junction
- Designed and qualified according to JEDEC®-JESD 47
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

APPLICATIONS

- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

DESCRIPTION

The VS-20ETF..S-M3 soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	20 A
V_R	800 V, 1000 V, 1200 V
V_F at I_F	1.31 V
I_{FSM}	355 A
t_{rr}	95 ns
T_J max.	150 °C
Snap factor	0.6
Package	D ² PAK (TO-263AB)
Circuit configuration	Single

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Sinusoidal waveform	20	A
V_{RRM}		800 to 1200	V
I_{FSM}		355	A
V_F	20 A, $T_J = 25$ °C	1.31	V
t_{rr}	1 A, 100 A/μs	95	ns
T_J	Range	-40 to +150	°C

VOLTAGE RATINGS

PART NUMBER	V_{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} AT 150 °C mA
20ETF08S-M3	800	900	6
20ETF10S-M3	1000	1100	
20ETF12S-M3	1200	1300	

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 97$ °C, 180° conduction half sine wave	20	A
Maximum peak one cycle non-repetitive surge current	I_{FSM}	10 ms sine pulse, rated V_{RRM} applied	300	
		10 ms sine pulse, no voltage reapplied	355	
Maximum I^2t for fusing	I^2t	10 ms sine pulse, rated V_{RRM} applied	450	A ² s
		10 ms sine pulse, no voltage reapplied	635	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1$ ms to 10 ms, no voltage reapplied	6350	A ² √s

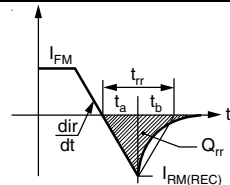


ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum forward voltage drop	V_{FM}	20 A, $T_J = 25\text{ }^{\circ}\text{C}$	1.31	V
Forward slope resistance	r_t	$T_J = 150\text{ }^{\circ}\text{C}$	11.88	$\text{m}\Omega$
Threshold voltage	$V_{F(TO)}$		0.93	V
Maximum reverse leakage current	I_{RM}	$T_J = 25\text{ }^{\circ}\text{C}$	0.1	mA
		$T_J = 150\text{ }^{\circ}\text{C}$	6	

RECOVERY CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Reverse recovery time	t_{rr}	I_F at 20 A _{pk} 25 A/ μs 25 $^{\circ}\text{C}$	400	ns
Reverse recovery current	I_{rr}		6.1	A
Reverse recovery charge	Q_{rr}		1.7	μC
Snap factor	S	Typical	0.6	



THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}		-40 to +150	$^{\circ}\text{C}$
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	0.9	$^{\circ}\text{C/W}$
Maximum thermal resistance, junction to ambient (PCB mount)	$R_{thJA}^{(1)}$		62	
Approximate weight			2	g
			0.07	oz.
Marking device		Case style D ² PAK (TO-263AB)	20ETF08S	
			20ETF10S	
			20ETF12S	

Note

- (1) When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 $^{\circ}\text{C/W}$. For recommended footprint and soldering techniques refer to application note #AN-994

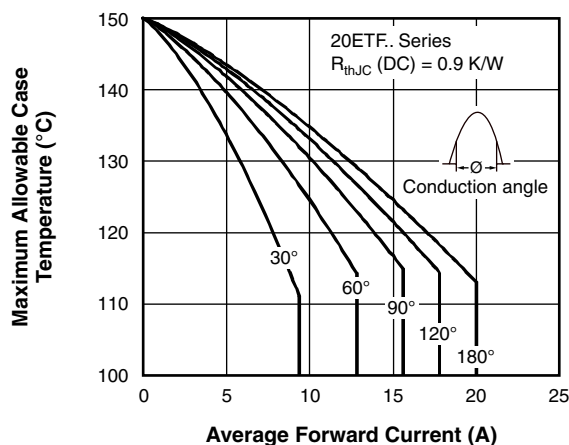


Fig. 1 - Current Rating Characteristics

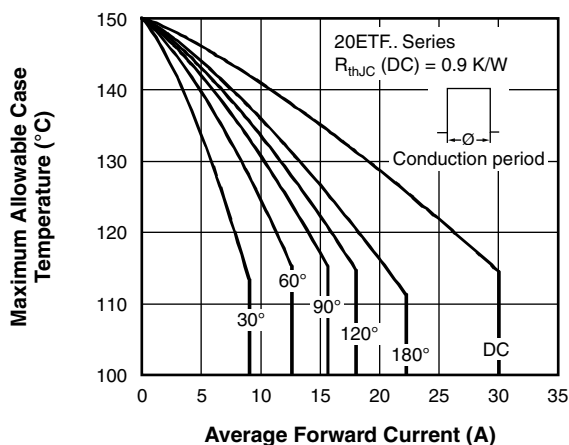


Fig. 2 - Current Rating Characteristics

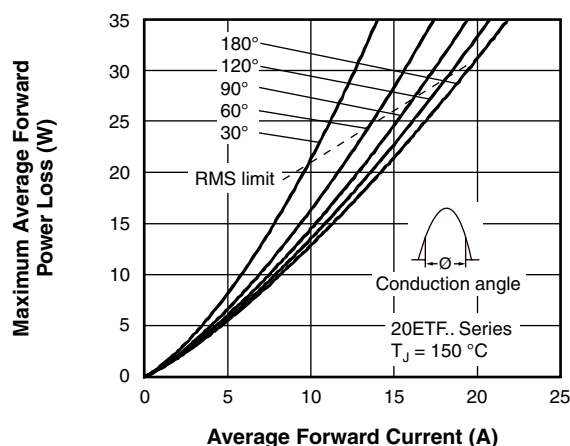


Fig. 3 - Forward Power Loss Characteristics

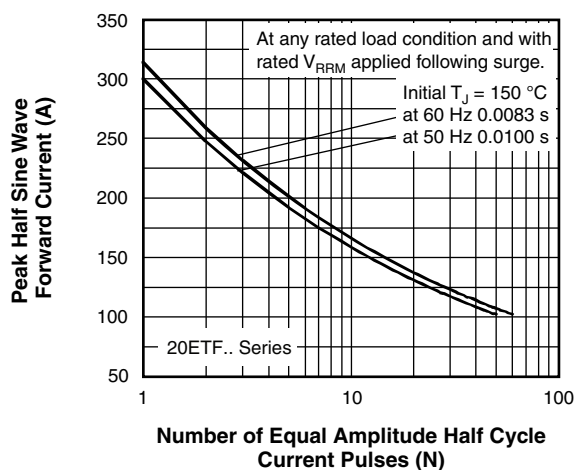


Fig. 5 - Maximum Non-Repetitive Surge Current

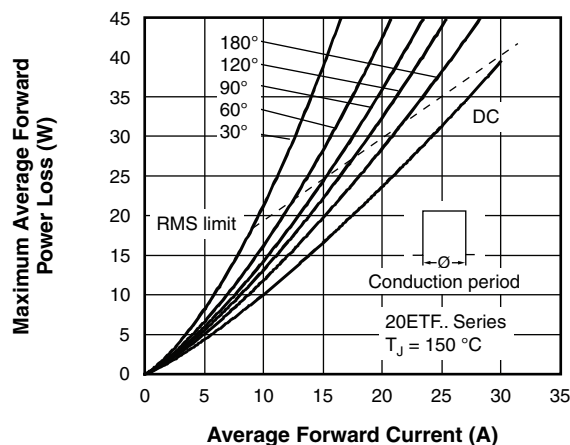


Fig. 4 - Forward Power Loss Characteristics

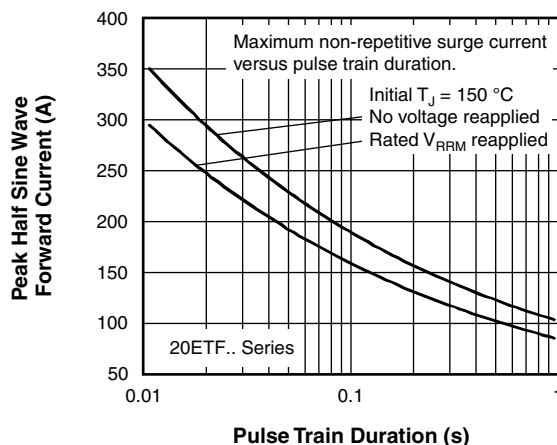


Fig. 6 - Maximum Non-Repetitive Surge Current

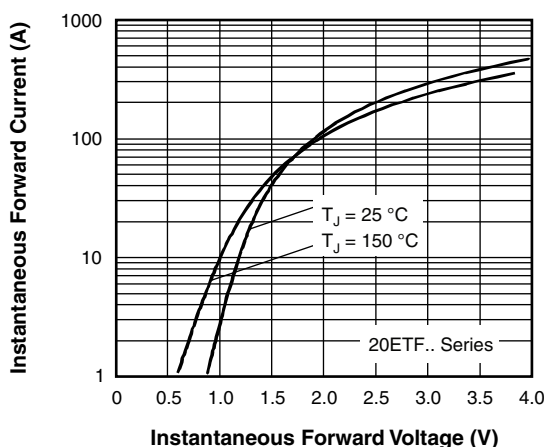


Fig. 7 - Forward Voltage Drop Characteristics

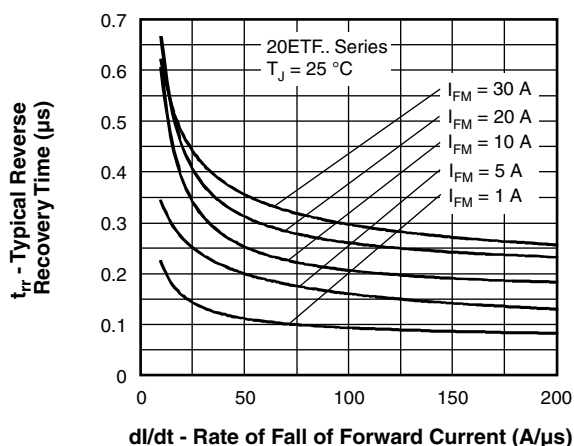


Fig. 8 - Recovery Time Characteristics, $T_J = 25^\circ C$

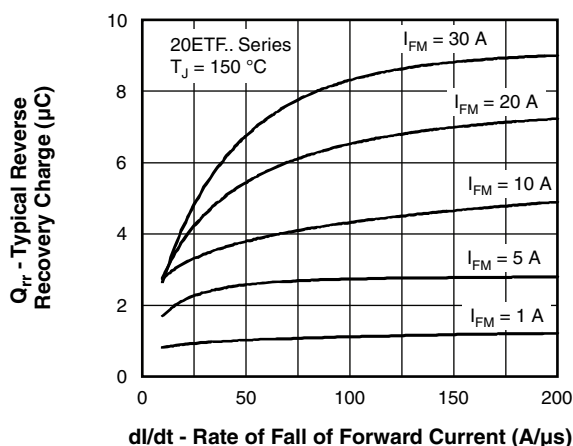


Fig. 11 - Recovery Charge Characteristics, $T_J = 150^\circ C$

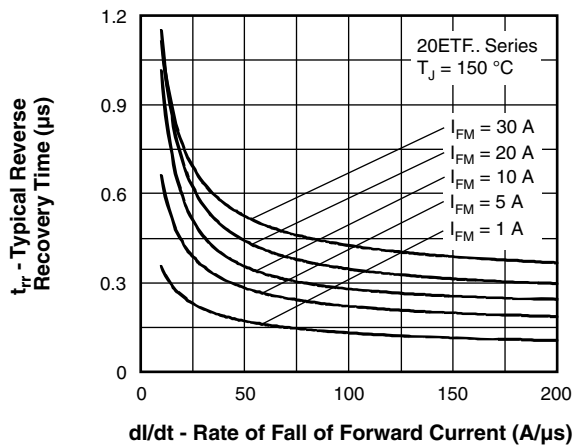


Fig. 9 - Recovery Time Characteristics, $T_J = 150^\circ C$

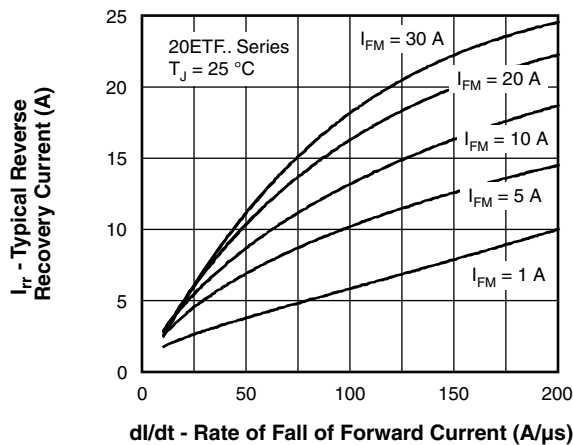


Fig. 12 - Recovery Current Characteristics, $T_J = 25^\circ C$

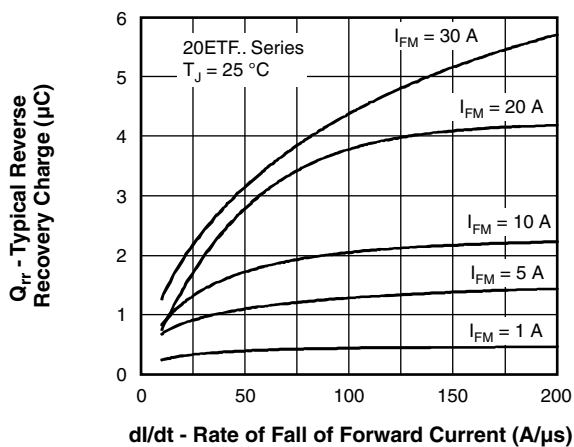


Fig. 10 - Recovery Charge Characteristics, $T_J = 25^\circ C$

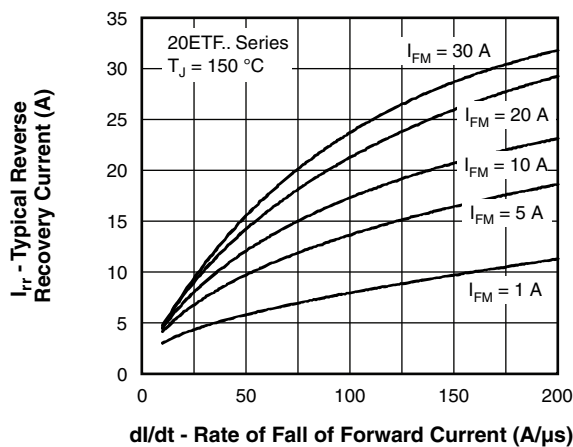


Fig. 13 - Recovery Current Characteristics, $T_J = 150^\circ C$

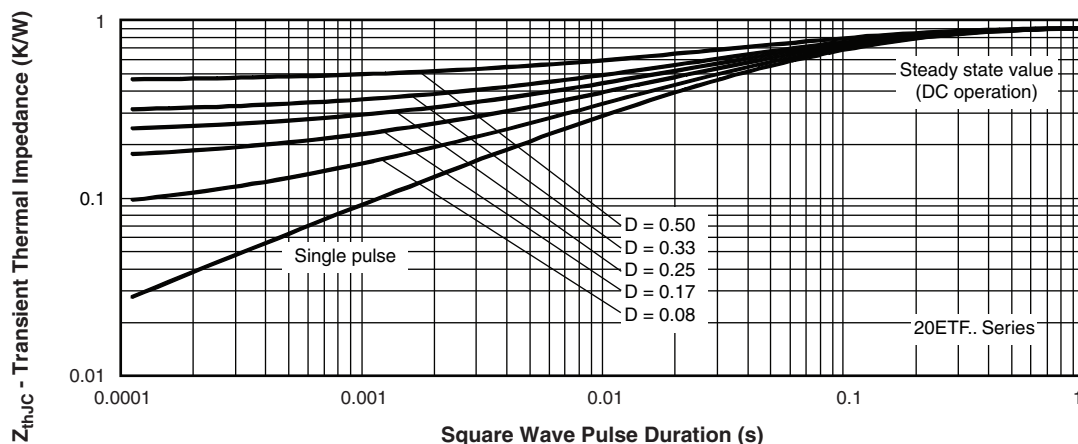


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code	VS-	20	E	T	F	12	S	TRL	-M3
	1	2	3	4	5	6	7	8	9

- | | | | |
|----------|---|---|-------------|
| 1 | - | Vishay Semiconductors product | |
| 2 | - | Current rating (20 = 20 A) | |
| 3 | - | Circuit configuration: | |
| | | E = single | |
| 4 | - | Package: | |
| | | T = D ² PAK (TO-263AB) | |
| 5 | - | Type of silicon: | |
| | | F = fast soft recovery rectifier | |
| 6 | - | Voltage code x 100 = V_{RRM} | 08 = 800 V |
| 7 | - | S = surface mountable | 10 = 1000 V |
| | | | 12 = 1200 V |
| 8 | - | • None = tape | |
| | | • TRR = tape and reel (right oriented) | |
| | | • TRL = tape and reel (left oriented) | |
| 9 | - | -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free | |



VS-20ETF08S-M3, VS-20ETF10S-M3, VS-20ETF12S-M3

www.vishay.com

Vishay Semiconductors

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-20ETF08S-M3	50	1000	Antistatic plastic tubes
VS-20ETF08STRR-M3	800	800	13" diameter reel
VS-20ETF08STRL-M3	800	800	13" diameter reel
VS-20ETF10S-M3	50	1000	Antistatic plastic tubes
VS-20ETF10STRR-M3	800	800	13" diameter reel
VS-20ETF10STRL-M3	800	800	13" diameter reel
VS-20ETF12S-M3	50	1000	Antistatic plastic tubes
VS-20ETF12STRR-M3	800	800	13" diameter reel
VS-20ETF12STRL-M3	800	800	13" diameter reel

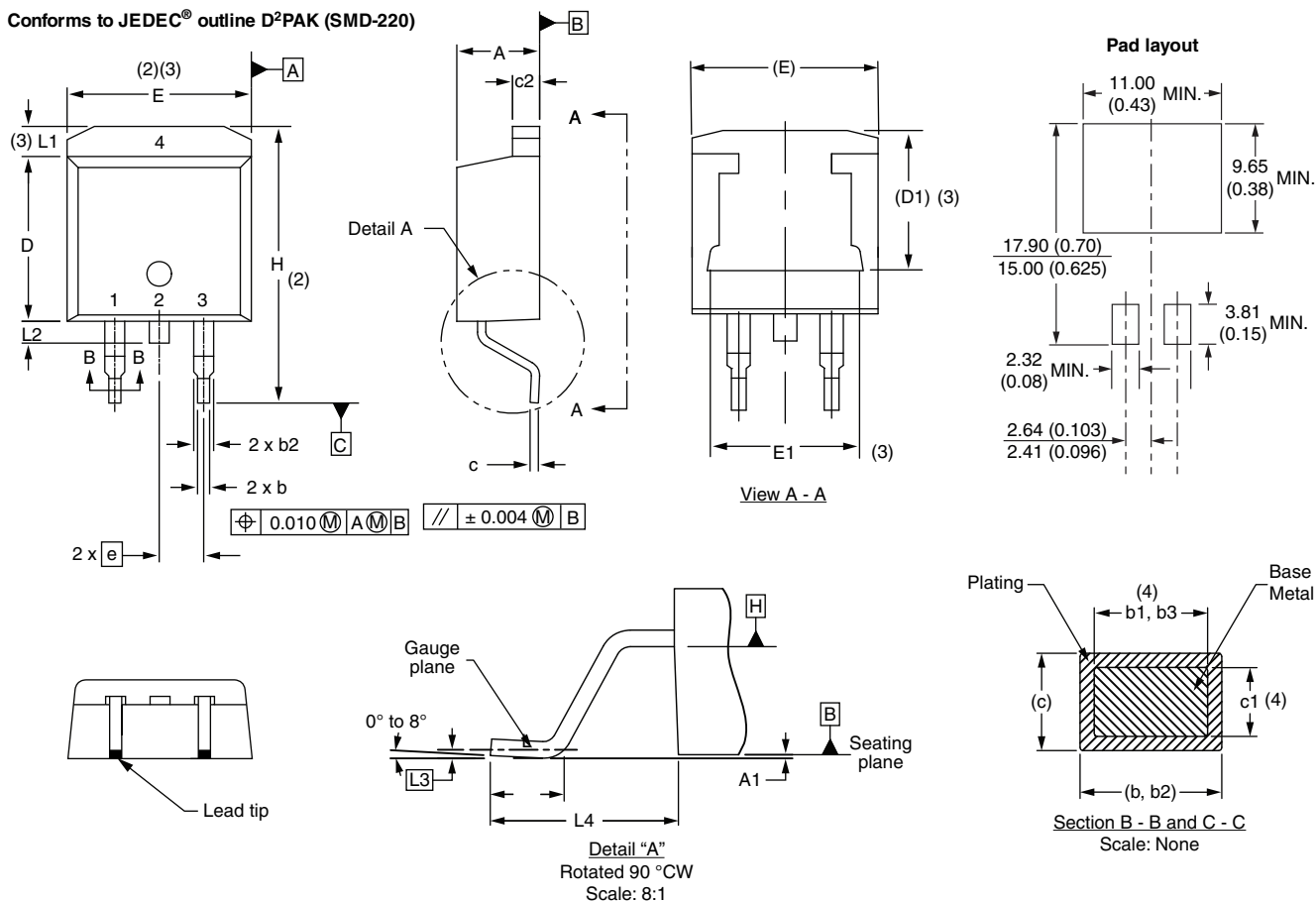
LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?96164
Part marking information	www.vishay.com/doc?95444
Packaging information	www.vishay.com/doc?96424



D²PAK

DIMENSIONS in millimeters and inches

Conforms to JEDEC® outline D²PAK (SMD-220)



SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
c	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
e	2.54 BSC		0.100 BSC		
H	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010 BSC		
L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB



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